

April 2008

# **BAX16**

# **High Voltage General Purpose Diode**



DO-35 Glass case

COLOR BAND DENOTES CATHODE

# Absolute Maximum Ratings \*Ta = 25°C unless otherwise noted

Symbol	Parameter	Value	Unit
V <sub>RRM</sub>	Maximum Repetitive Reverse Voltage	150	V
I <sub>F(AV)</sub>	Average Rectified Forward Current	200	mA
i <sub>f</sub>	Recurrent Peak Forward Current	600	mA
I <sub>FSM</sub>	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 s Pulse Width = 1.0 μs	1 4	A A
T <sub>STG</sub>	Storage Temperature Range	-65 to 200	°C
T <sub>J</sub>	Operating Junction Temperature	175	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of the diode may be impaired.

## Electrical Characteristics \* Ta = 25°C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Max.	Units
$V_R$	Breakdown Voltage	I <sub>R</sub> = 100μA	180		V
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 1.0mA		0.65	V
V <sub>FP</sub>	Forward Voltage Pulse Width = 300μs	I <sub>F</sub> = 100mA I <sub>F</sub> = 200mA		1.3 1.5	
I <sub>R</sub>	Reverse Leakage	V <sub>R</sub> = 50V V <sub>R</sub> = 50V, T <sub>A</sub> = 150°C V <sub>R</sub> = 150V V <sub>R</sub> = 150V, T <sub>A</sub> = 150°C		25 25 100 100	nA μA nA μA
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 30 \text{mA}, I_R = 30 \text{mA},$ $I_{rr} = 1.0 \text{mA}, R_L = 100 \Omega$		120	ns

Notes:

1) These ratings are based on a maximum junction temperature of 200degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# **Typical Performance Characteristics**

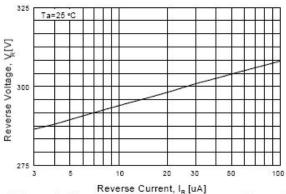
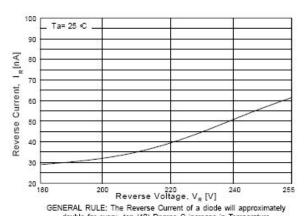


Figure 1. Reverse Voltage vs Reverse Current BV - 1.0 to 100uA



GENERAL RULE: The Reverse Current of a diode will approximately double for every ten (10) Degree C increase in Temperature
Figure 3. Reverse Current vs Reverse Roltage
IR - 180 to 225 V

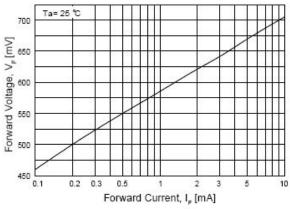


Figure 5. Forward Voltage vs Forward Current VF - 0.1 to 10mA

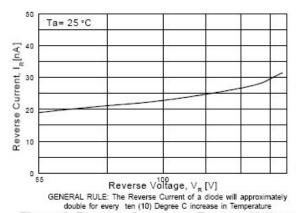


Figure 2. Reverse Current vs Reverse Voltage IR - 55 to 205 V

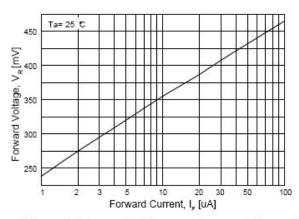


Figure 4. Forward Voltage vs Forward Current VF - 1.0 to 100uA

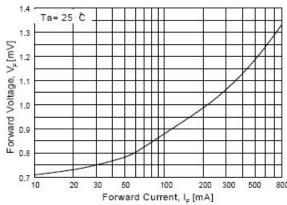


Figure 6. Forward Voltage vs Forward Current VF - 10 to 800mA

# **Typical Performance Characteristics**

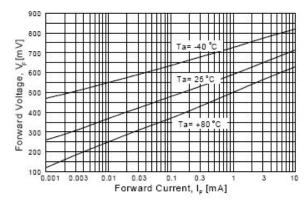


Figure 7. Forward Voltage vs Ambient Temperature VF - 1.0 uA - 10 mA (-40 to +80 Deg C)

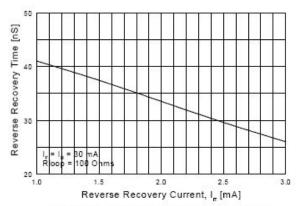


Figure 9. Reverse Recovery Time vs Reverse Recovery Current

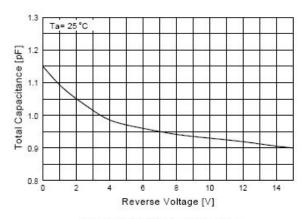


Figure 8. Total Capacitance

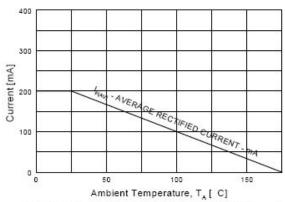


Figure 10. Average Rectified Current (I<sub>F(AV)</sub>) versus Ambient Temperature (T<sub>A</sub>)

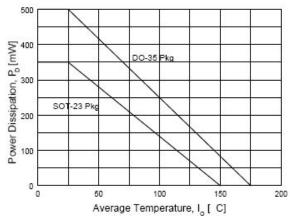


Figure 11. Power Derating Curve





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